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With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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| | ITC100P | Units |
|-------------------------------|---------|-------|
| Hook Switch Breakdown Voltage | 350 | V |
| Bridge Rectifier Reverse | | |
| Voltage | 350 | V |
| Darlington Collector Current | 120 | mA |

Features

- Small 16 Pin SOIC Package (PCMCIA Compatible)
- Board Space and Cost Savings
- No Moving Parts
- 3750V_{RMS} Input/Output Isolation
 FCC Compatible Part 68
- · Photodarlington Hook Switch
- Full-Wave Bridge Rectifier
- Darlington Transistor for Electronic Inductor "Dry" Circuits
- Half Wave Current Detector for Ring Signal or Loop **Current Detect**
- · JEDEC Standard Pin Out

Applications

- Data/Fax Modem
- · Voice Mail Systems
- Telephone Sets
- · Computer Telephony Integration
- Set Top Box Modems

Description

The Integrated Telecom Circuit combines a high voltage optically isolated photodarlington, bridge rectifier, Darlington transistor and optocoupler into one 16 pin SOIC package, consolidating designs and reducing component count in telecom applications. The ITC100's optocoupler provides for half wave detection of ring signals.

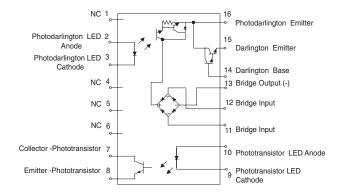
Approvals

- UL Recognized
- EN 60950

Ordering Information

| Part # | Description |
|-----------|-------------------------|
| ITC100P | 16 Pin SOIC (50/Tube) |
| ITC100PTR | 16 Pin SOIC (1000/Reel) |

Pin Configuration





Absolute Maximum Ratings (@ 25° C)

| Parameter | Min | Тур | Max | Units |
|--|------|-----|----------------|------------------|
| Total Package Dissipation | - | - | 1 ¹ | W |
| Isolation Voltage | | | | |
| Input to Output | 3750 | - | - | V _{RMS} |
| Operational Temperature | -40 | - | +85 | °C |
| Storage Temperature | -40 | - | +125 | °C |
| Soldering Temperature (10 Seconds Max.) | - | - | +220 | °C |

¹ Above 25° derate linerity 8.33mw/°C

Total Power Dissipation (PD):

$$\begin{split} &P_D = P_{HOOKSWITCH} + P_{BRIDGE} + P_{DARLINGTON} + P_{LED} \\ &P_D = (R_{DS}(on)) \; (I^2_L) + 2(V_F)(I_L) + (V_{CE})(I_L) + (V_{LED})(I_F) \end{split}$$

R_{DS}(on) = Maximum realy on resistance

= Maximum loop current

= Maximum diode forward voltage

 V_{CE} = Maximum voltage collector to emitter

 V_{LED} = Maximum LED forward voltage

= Maximum LED current

Absolute Maximum Ratings are stress ratings. Stresses in excess of these ratings can cause permanent damage to the device. Functional operation of the device at conditions beyond those indicated in the operational sections of this data sheet is not implied.

Electrical Characteristics

| Parameter | Condition | Symbol | Min | Тур | Max | Units |
|--|---|---|------|-----|-------|-------|
| Photodarlington Portion | | | | | | |
| Collector-Emitter Breakdown voltage | I _C = 100uA | B _{VCEO} | 350 | - | - | V |
| Collector Dark Current | V _{CE} = 200V | I _{CEO} | - | - | 100 | nA |
| Collector Emitter Saturation Voltage | $I_C = 100 \text{mA}$ $I_B = 150 \text{uA}$ | V _{CE(S)} | - | - | 1.2 | V |
| Current Gain | Hfe | I _C = 40mA V _{CE} =2V | 2500 | - | 40000 | - |
| LED Input control Current | - | I _F | 5 | - | 50 | mA |
| LED input Voltage Drop | $I_F = 5mA$ | V _F | 0.9 | 1.2 | 1.4 | V |
| LED Reverse Input Voltage | - | V _R | - | - | 5 | V |
| LED Reverse Input Current | I _R = 5V | I _R | - | - | 10 | mA |
| Phototransistor Portion | | | | | | |
| Phototransitor Blocking Voltage | $I_C = 10uA$ | B _{VCEO} | 20 | 50 | - | V |
| Phototransistor Dark Current | $V_{CC} = 5V$ $I_F = 0mA$ | I _{CEO} | - | 50 | 500 | mA |
| Saturation Voltage | I _C = 2mA I _F = 16mA | V _{SAT} | - | 0.3 | 0.5 | V |
| Current Transfer Ratio | $V_{CE} = 0.5V$ $I_F = 6mA$ | CTR | 33 | 400 | - | % |
| LED Input control Current | $V_{CE} = 0.5V$ $I_{C} = 2mA$ | I _F | 6 | 2 | 100 | mA |
| LED input Voltage Drop | I _F = 5mA | V _F | 0.9 | 1.2 | 1.4 | V |
| LED Input Current (Detector must be off) | $V_{CE} = 5V$ $I_{C} = 10uA$ | I _F | 5 | 25 | - | uA |
| Bridge Rectifier Portion | | | | | | |
| Reverse Voltage | | V _{RD} | - | - | 350 | V |
| Forward Voltage Drop | I _{FD} = 120mA | V _{FD} | - | - | 1.1 | V |

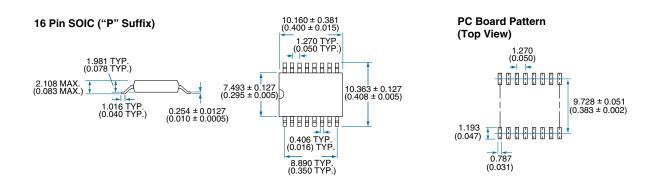


Electrical Characteristics

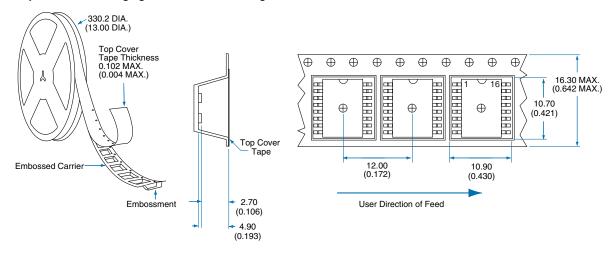
| Parameter | Condition | Symbol | Min | Тур | Max | Units |
|-------------------------------|-------------------------|----------------------|-----|-----|-----|-------|
| Reverse Leakage Current | T _J = 25°C | I _{RD} | - | - | 10 | uA |
| | V _R = 350V | | | | | |
| | T _J = 85°C | | | | 50 | uA |
| Forward Current Continuous | | I _{FD} | - | - | 140 | mA |
| Forward Current Peak | T= 10mS | I _{FD} | - | - | 0.5 | А |
| Darlington Portion | | | | | | |
| Collector Emitter Voltage | I _C =10mA DC | V _{CEO} | 20 | - | - | V |
| | I _B =0 | | | | | |
| Collector Current Continous | V _C =3.5V | I _C | - | - | 120 | mA |
| Off – State Collector Emitter | V _{CE} =10V | I _{CEX} | - | - | 1 | uA |
| Leakage Current | I _B =0mA | | | | | |
| DC Gain Current | V _{CE} =5VDC | h _{FE} | 300 | - | - | - |
| | I _C =100mA | | | | | |
| Saturation Voltage | I _C =120mA | V _{CE(SAT)} | - | - | 1.5 | V |
| Total Harmonic Distortion | F ₀ =300Hz @ | - | - | - | -80 | dB |
| | -10dBm | | | | | |
| | I _C =40mA | | | | | |



MECHANICAL DIMENSIONS



Tape and Reel Packaging for 16 Pin SOIC Package



Dimensions mm (inches)

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